

Peak Emission Wavelength: 850nm

The 850nm IR emitter series is designed for applications requiring high output and precise optical / mechanical axis alignment. Custom package solutions and sorting are available..

FEATURES

- > High Output Power
- > Wide Beam Angle
- > High Reliability

APPLICATIONS

- > Optical Switches & Sensors
- > Fiber Optical Communication
- > Bar-code Reader



Absolute Maximum Ratings (Ta=25°C)

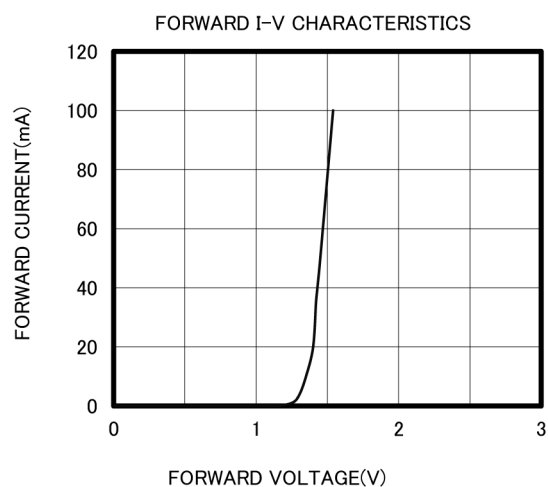
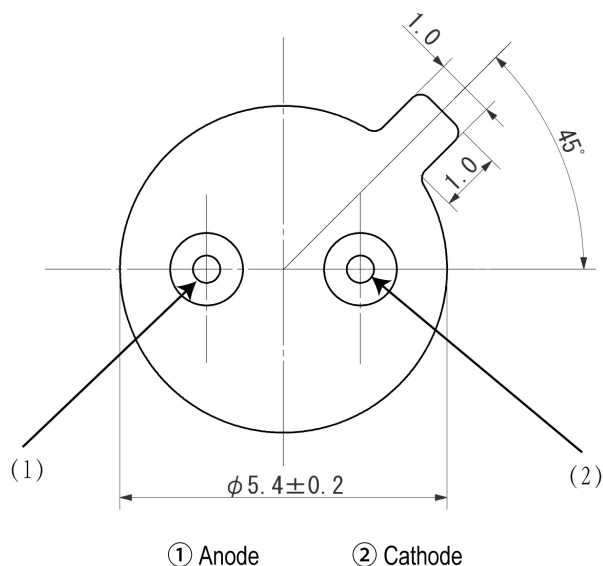
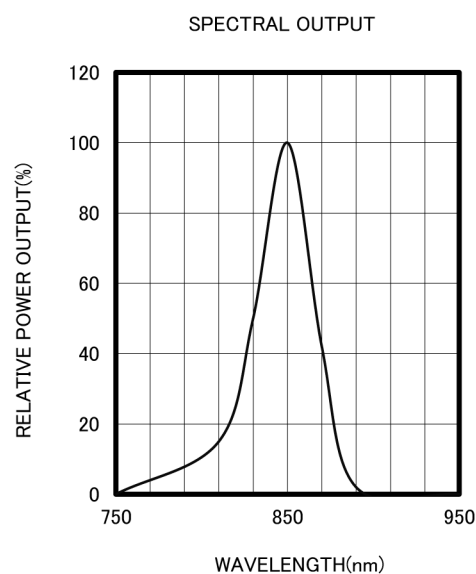
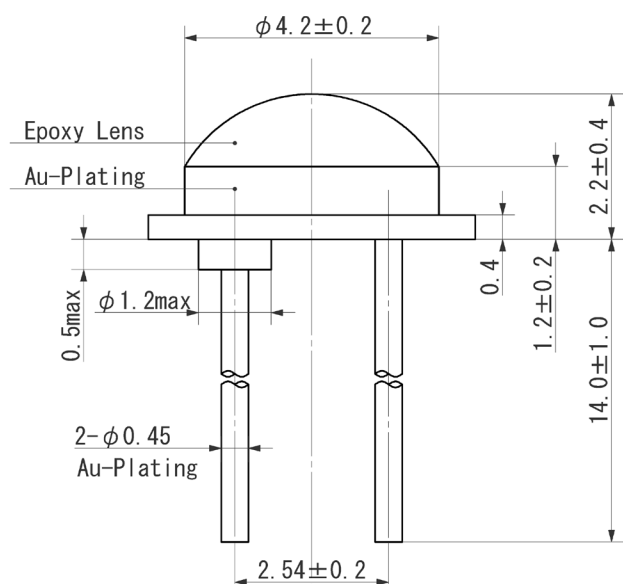


ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	100	mA
Forward Current (Pulse)*1	IFP	1	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	190	mW
Operating Temperature Range	Topr	-20 ~ +80	°C
Storage Temperature Range	Tstg	-30 ~ +100	°C
Junction Temperature	Tj	100	°C
Lead Soldering Temperature*2	Tls	260	°C

*1: Tw=10μsec, T=10msec. *2: Time 5Sec max, Position: Up to 3mm from the body.

Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=50mA	--	30.0	--	mW
Radiant Intensity	IE	IF=50mA	--	9.3	--	mW/sr
Forward Voltage	VF	IF=50mA	--	1.46	1.8	V
Reverse Current	IR	VR=5V	--	--	100	μA
Peak Emission Wavelength	λp	IF=50mA	--	850	--	nm
Spectral Line Half Width	Δλ	IF=50mA	--	30	--	nm
Half Intensity Beam Angle	Θ	IF=50mA	--	±75	--	deg
Switching Times	Tr, Tf	IF=50mA	--	150, 100	--	ns



Unit: mm, Tolerance: ± 0.2

